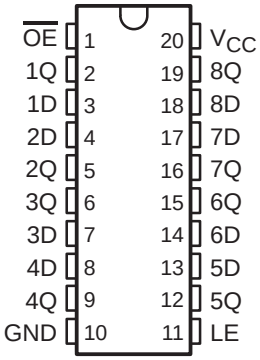
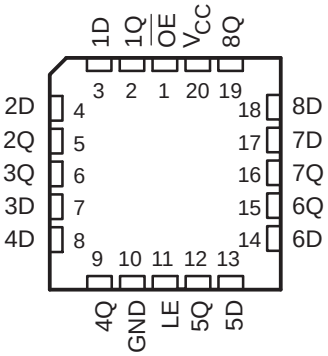
- ***EPIC***™ **(Enhanced-Performance Implanted CMOS) Process**
- **Inputs Are TTL-Voltage Compatible**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**
- **Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs**

SN54AHCT373 . . . J OR W PACKAGE
SN74AHCT373 . . . DB, DGV, DW, N, OR PW PACKAGE
(TOP VIEW)



SN54AHCT373 . . . FK PACKAGE
(TOP VIEW)



description

The ’AHCT373 devices are octal-transparent D-type latches. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is low, the Q outputs are latched at the logic levels of the D inputs.

A buffered output-enable ($\overline{OE}$) input can be used to place the eight outputs in either a normal logic state (high or low) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

$\overline{OE}$ does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

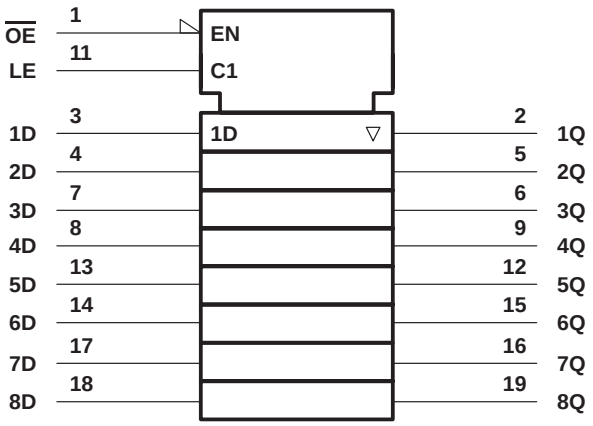
To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHCT373 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AHCT373 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE
(each latch)

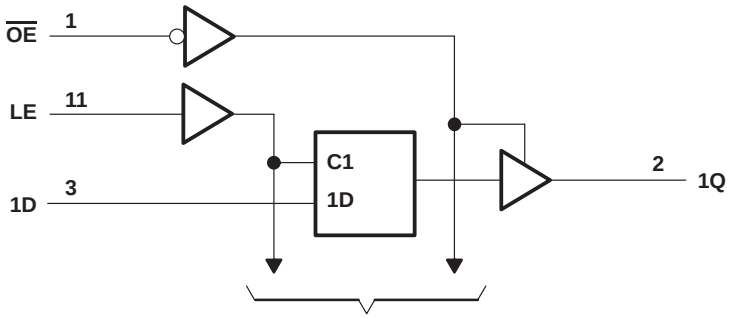
INPUTS			OUTPUT
$\overline{OE}$	LE	D	Q
L	H	H	H
L	H	L	L
L	L	X	Q_0
H	X	X	Z

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V_{CC} . . . . . –0.5 V to 7 V
Input voltage range, V_I (see Note 1) . . . . . –0.5 V to 7 V
Output voltage range, V_O (see Note 1) . . . . . –0.5 V to V_{CC} + 0.5 V
Input clamp current, I_{IK} (V_I < 0) . . . . . –20 mA
Output clamp current, I_{OK} (V_O < 0 or V_O > V_{CC}) . . . . . ±20 mA
Continuous output current, I_O (V_O = 0 to V_{CC}) . . . . . ±25 mA
Continuous current through V_{CC} or GND . . . . . ±75 mA
Package thermal impedance, θ_{JA} (see Note 2): DB package . . . . . 70°C/W
DGV package . . . . . 92°C/W
DW package . . . . . 58°C/W
N package . . . . . 69°C/W
PW package . . . . . 83°C/W
Storage temperature range, T_{stg} . . . . . –65°C to 150°C

‡ Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 3)

		SN54AHCT373		SN74AHCT373		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage	0	5.5	0	5.5	V
V_O	Output voltage	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current		–8		–8	mA
I_{OL}	Low-level output current		8		8	mA
$\Delta t/\Delta v$	Input transition rise or fall rate		20		20	ns/V
T_A	Operating free-air temperature	–55	125	–40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V_{CC}	T_A = 25°C			SN54AHCT373		SN74AHCT373		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V_{OH}	I_{OH} = –50 μA	4.5 V	4.4	4.5		4.4		4.4		V
	I_{OH} = –8 mA		3.94			3.8		3.8		
V_{OL}	I_{OL} = 50 μA	4.5 V			0.1		0.1		0.1	V
	I_{OL} = 8 mA				0.36		0.44		0.44	
I_{OZ}	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5		±2.5	μA
I_I	$V_I = V_{CC}$ or GND	0 V to 5.5 V			±0.1		±1*		±1	μA
I_{CC}	$V_I = V_{CC}$ or GND, I_O = 0	5.5 V			4		40		40	μA
ΔI_{CC}†	One input at 3.4 V, Other inputs at V_{CC} or GND	5.5 V			1.35		1.5		1.5	mA
C_i	$V_I = V_{CC}$ or GND	5 V		4	10				10	pF
C_o	$V_O = V_{CC}$ or GND	5 V		9						pF

* On products compliant to MIL-PRF-38535, this parameter is not production tested at V_{CC} = 0 V.
† This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

timing requirements over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

		T_A = 25°C		SN54AHCT373		SN74AHCT373		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
t_w	Pulse duration, $\overline{LE}$ high	6.5		6.5		6.5		ns
t_{su}	Setup time, data before $\overline{LE}\downarrow$	1.5		1.5		1.5		ns
t_h	Hold time, data after $\overline{LE}\downarrow$	3.5		3.5		3.5		ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T_A = 25°C			SN54AHCT373		SN74AHCT373		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	D	Q	C_L = 15 pF		5.1*	8.5*	1*	9.5*	1	9.5	ns
t_{PHL}					5.1*	8.5*	1*	9.5*	1	9.5	
t_{PLH}	LE	Q	C_L = 15 pF		7.7*	12.3*	1*	13.5*	1	13.5	ns
t_{PHL}					7.7*	12.3*	1*	13.5*	1	13.5	
t_{PZH}	$\overline{OE}$	Q	C_L = 15 pF		6.3*	10.9*	1*	12.5*	1	12.5	ns
t_{PZL}					6.3*	10.9*	1*	12.5*	1	12.5	
t_{PHZ}	$\overline{OE}$	Q	C_L = 15 pF		6*	10.2*	1*	11*	1	11	ns
t_{PLZ}					6*	10.2*	1*	11*	1	11	
t_{PLH}	D	Q	C_L = 50 pF		5.9	9.5	1	10.5	1	10.5	ns
t_{PHL}					5.9	9.5	1	10.5	1	10.5	
t_{PLH}	LE	Q	C_L = 50 pF		8.5	13.3	1	14.5	1	14.5	ns
t_{PHL}					8.5	13.3	1	14.5	1	14.5	
t_{PZH}	$\overline{OE}$	Q	C_L = 50 pF		7.1	11.9	1	13.5	1	13.5	ns
t_{PZL}					7.1	11.9	1	13.5	1	13.5	
t_{PHZ}	$\overline{OE}$	Q	C_L = 50 pF		6.8	11.2	1	12	1	12	ns
t_{PLZ}					6.8	11.2	1	12	1	12	
$t_{sk(o)}$			C_L = 50 pF			1**				1	ns

* On products compliant to MIL-PRF-38535, this parameter is not production tested.
** On products compliant to MIL-PRF-38535, this parameter does not apply.

noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C (see Note 4)

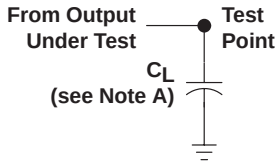
PARAMETER		SN74AHCT373			UNIT
		MIN	TYP	MAX	
$V_{OL(P)}$	Quiet output, maximum dynamic V_{OL}		0.8	1.2	V
$V_{OL(V)}$	Quiet output, minimum dynamic V_{OL}		–0.8	–1.2	V
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}	4.1			V
$V_{IH(D)}$	High-level dynamic input voltage	2			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V

NOTE 4: Characteristics are for surface-mount packages only.

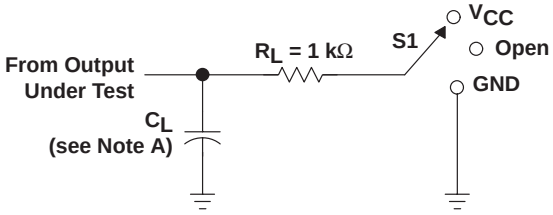
operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		TYP	UNIT
C_{pd}	Power dissipation capacitance	No load,	f = 1 MHz	17	pF

PARAMETER MEASUREMENT INFORMATION

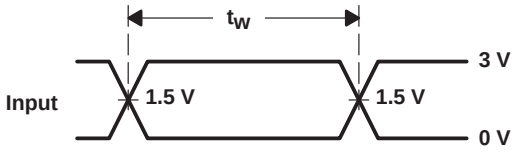


LOAD CIRCUIT FOR
TOTEM-POLE OUTPUTS

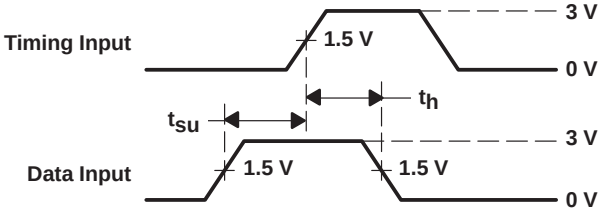


LOAD CIRCUIT FOR
3-STATE AND OPEN-DRAIN OUTPUTS

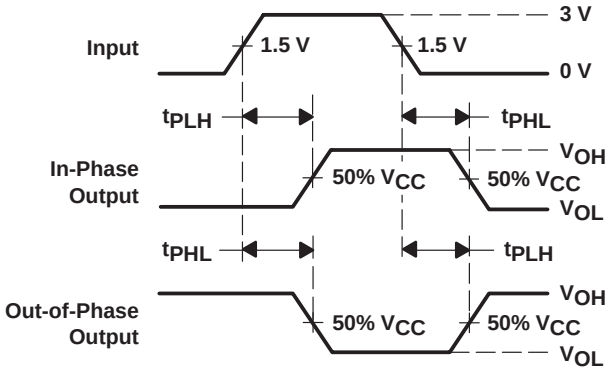
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{CC}
t_{PHZ}/t_{PZH}	GND
Open Drain	V_{CC}



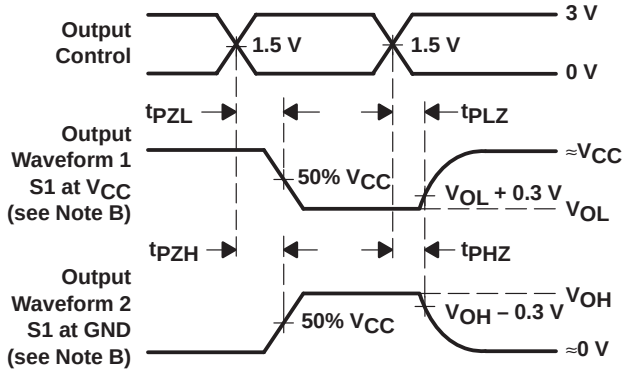
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_r ≤ 3 ns, t_f ≤ 3 ns.
D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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SN54AHCT373, Octal Transparent D-type Latches With 3-State Outputs

Device Status: Active

Parameter Name	SN54AHCT373
Voltage Nodes (V)	5
Vcc range (V)	4.5 to 5.5
Input Level	TTL
Output Level	CMOS
Output Drive (mA)	-8/8
No. of Outputs	8
Static Current	0.04
th (ns)	3.5
tpd(max) (ns)	14.5
tsu (ns)	1.5
Logic	True

Description

The 'AHCT373 devices are octal-transparent D-type latches. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is low, the Q outputs are latched at the logic levels of the D inputs.

A buffered output-enable (OE\) input can be used to place the eight outputs in either a normal logic state (high or low) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

OE\ does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, OE\ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHCT373 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AHCT373 is characterized for operation from -40°C to 85°C.

Features

- *EPIC*™ (Enhanced-Performance Implanted CMOS) Process
- Inputs Are TTL-Voltage Compatible
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- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs

Datasheets

Full datasheet in Acrobat PDF: scls239k.pdf (87 KB)
Full datasheet in Zipped PostScript: scls239k.psz (97 KB)

Pricing/Samples/Availability

Orderable Device	Package	Pins	Temp (°C)	Status	Price/unit USD (100-999)	Pack Qty	DSCC Number	Availability / Samples
5962-9686701QRA	J	20	-55 TO 125	ACTIVE	2.71	1		Check stock or order
SNJ54AHCT373FK	FK	20	-55 TO 125	ACTIVE	10.77	1	5962-9686701Q2A	Check stock or order
SNJ54AHCT373J	J	20	-55 TO 125	ACTIVE	2.71	1	5962-9686701QRA	Check stock or order

SNJ54AHCT373W	W	20	-55 TO 125	ACTIVE	11.52	1	5962-9686701QSA	Check stock or order

Application Reports

View Application Reports for Digital Logic

- AHC/AHCT Designer's Guide February 2000 (SCLA013D - Updated: 02/24/2000)
- Advanced High-Speed CMOS (AHC) Logic Family (SCAA034B - Updated: 01/01/1998)
- Bus-Interface Devices With Output-Damping Resistors Or Reduced-Drive Outputs (SCBA012A - Updated: 08/01/1997)
- CMOS Power Consumption And CPD Calculation (SCAA035B - Updated: 06/01/1997)
- Implications Of Slow Or Floating CMOS Inputs (SCBA004C - Updated: 02/01/1998)
- Live Insertion (SDYA012 - Updated: 10/01/1996)
- Migration From 3.3-V To 2.5-V Power Supplies For Logic Devices (SCEA005 - Updated: 12/01/1997)

Related Documents

- Documentation Rules (SAP) And Ordering Information (SZZU001B, 4 KB - Updated: 05/06/1999)
- Logic Selection Guide Second Half 2000 (SDYU001N, 5035 KB - Updated: 04/17/2000)
- MicroStar Junior BGA Design Summary (SCET004, 284 KB - Updated: 07/28/2000)
- More Power In Less Space - Technical Article (SCAU001A, 850 KB - Updated: 03/01/1996)

Table Data Updated on: 9/7/2000